## UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 7,547,909 B2 Page 1 of 1

APPLICATION NO.: 10/597607
DATED: June 16, 2009
INVENTOR(S): Joongseo Park

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title Page

Item (54)

Please delete "III\_NITRIDE COMPOUND ICE SEMICONDUCTOR LIGHT EMITTING DEV" and insert --III-NITRIDE COMPOUND SEMICONDUCTOR LIGHT EMITTING DEVICE--

Item (22)

Please delete "March 5, 2005" and insert -- February 5, 2005--

Item (86)

For the filing or '371c' date, delete "August 1, 2006" and insert --August 3, 2006--

Signed and Sealed this

Fifteenth Day of September, 2009

David J. Kappos

David J. Kappos

Director of the United States Patent and Trademark Office